



High-Performance CMOS Two-Channel SP4T Mux/Demux

QS4A210Q

FEATURES

- Low On-resistance: $r_{DS(on)} = 5\Omega$
- Fast transition time: t_{TRAN} = 6ns
- Wide bandwidth: 700MHz (–3dB point)
- Crosstalk:
 - -110dB @ 50KHz, -68dB @ 5MHz,
 - -66dB @ 30MHz
- Off-isolation:
 - -90dB @ 50KHz, -60dB @ 5MHz,
 - -50dB @ 30MHz,
- Single 5V supply
- Can be used as a multiplexer or demultiplexer
- · TTL compatible control inputs
- Ultra-low quiescent current: 3µA

APPLICATIONS

- High-speed video signal switching/routing
- HDTV-quality video signal multiplexing
- Audio signal switching/routing
- · Data acquisition
- ATE systems
- Telecom routing
- · Switch between multiple video sources
- · Token Ring transceivers
- High-speed networking

GENERAL DESCRIPTION

The QS4A210Q is a high-performance CMOS Two-Channel SP4T multiplexer/demultiplexer with individual enables. The low on-resistance of the QS4A210Q allows inputs to be connected to outputs with low insertion loss and high bandwidth. TTL-compatible control circuitry with "Break-Before-Make" feature prevents contention.

The QS4A210Q with 700MHz bandwidth makes it ideal for high-performance video signal switching, audio signal switching, and telecom routing applications. Low power dissipation makes this device ideal for battery operated and remote instrumentation applications.

The QS4A210Q is offered in the QSOP package which has several advantages over conventional packages such as PDIP and SOIC including:

- Reduced signal delays due to denser component packaging on circuit boards
- Reduced system noise due to less pin inductance resulting in lower ground bounce

Figure 1. Functional Block Diagram

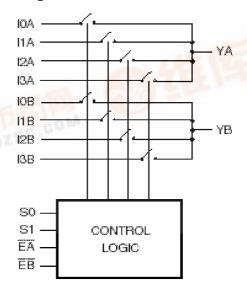




Figure 2. Pin Configuration

(All Pins Top View)

QSOP ĒĀ 🛛 1 16 🛮 Vac S1 🛮 2 15 🗖 🖽 14 🛭 50 13A 🛮 3 12A 🛮 4 13 🛮 138 12 🛮 128 11A 🛮 5 11 🛮 118 10A 🛮 6 YA 🛛 7 10 🛮 108 GND □ 8 9 🛮 YB

Table 1. Pin Definitions

Name	I/O	Description			
IxA	I/O	Demux Port A			
IxB	I/O	Demux Port B			
EA, EB	I	Enable Inputs			
S0, S1	I	Select Inputs			
YA, YB	I/O	Mux Port A, B			

Table 2. Function Table

Enable		Sel	ect	l	emux erts		
EΑ	EB	S1	S0	YA YB		Function	
Н	Х	Х	Х	High-Z	Х	Disable A	
Х	Н	Х	Х	Х	High-Z	Disable B	
L	L	L	L	I0A	I0B	S1-0 = 0	
L	L	L	Н	I1A	I1B	S1-0 = 1	
L	L	Н	L	I2A	I2B	S1-0 = 2	
L	L	Н	Н	I3A	I3B	S1-0 = 3	

Table 3. Absolute Maximum Ratings

Supply Voltage to Ground	–0.5V to +7.0V
DC Input Voltage V _{IN}	–0.5V to +7.0V
AC Input Voltage (for a pulse width ≤ 20ns)	
DC Output Current Max. Sink Current/Pin	120mA
Maximum Power Dissipation	0.7 watts
T _{STG} Storage Temperature	–65° to +150°C

Note: ABSOLUTE MAXIMUM RATINGS are those conditions beyond which damage to the device may occur. Exposure to these conditions or beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rating conditions is not implied.

Table 4. Electrical Characteristics Over Operating Range

Commercial: $T_A = 0$ °C to 70 °C, $V_{CC} = 5.0$ V ± 10%

Symbol	Parameter	Test Conditions	Min	Typ ⁽¹⁾	Max	Unit
Analog	Switch				•	
V _{IN}	Analog Signal Range(2)		-0.5	1.0	V _{CC} -1	٧
r _{DS(on)}	Drain-source On-resistance ^(2,3)	$V_{CC} = Min., V_{IN} = 0.0V,$ $I_{ON} = 30mA$		5	7	Ω
		$V_{CC} = Min., V_{IN} = 2.4V,$ $I_{ON} = 15mA$		5.5	8	Ω
$\Delta r_{DS(on)}$	r _{DS(on)} Matching Between Channels ⁽⁴⁾	$\begin{split} &V_{CC} = Min.,V_{IN} = 0.0V,\\ &I_{ON} = 30mA \end{split}$	_	1	_	Ω
		$V_{CC} = Min., V_{IN} = 2.4V,$ $I_{ON} = 15mA$	_	1	_	Ω
I _{C (OFF)}	Channel Off Leakage Current	$I_N = V_{CC}$ or 0V, $Y_N = 0V$ or V_{CC} EA = EB = V_{CC}		2	_	nA
I _{C (ON)}	Channel On Leakage Current	$I_N = Y_N = 0V$, Each Channel is Turned On Sequentially	_	2	_	nA
Digital	Control					
V _{IH}	Input HIGH Voltage	Guaranteed Logic HIGH for Control Pins	2.0	_	_	V
V _{IL}	Input LOW Voltage	Guaranteed Logic LOW for Control Pins		_	0.8	٧
Dynami	ic Characteristics					
t _{TRANS}	Switching Time of Mux Sn to Y	$R_L = 1K\Omega, C_L = 100pF$ (See Figure 9)	0.5		6.6	ns
t _{ON(EN)}	Enable Turn-on Time EA = EB to Y	$R_L = 1K\Omega$, $C_L = 100pF$ (See Figure 10)	0.5		6.0	ns
t _{OFF(EN)}	Enable Turn-off Time $EA = EB$ to Y	$R_L = 1K\Omega$, $C_L = 100pF$ (See Figure 10)	0.5		6.0	ns
t _{PD}	Group Delay(2,5)	$R_L = 1K\Omega$, $C_L = 100pF$	_	_	250	ns
f _{3dB}	-3dB Bandwidth	$V_{IN} = 1Vp-p, R_L = 75\Omega$	_	700		MHz
	Off-isolation	$V_{IN} = 1Vp-p, R_L = 75\Omega, f = 5.5MHz$	_	-60	_	dB
X _{TALK}	Crosstalk	$V_{IN} = 1Vp-p, R_L = 75\Omega, f = 5.5MHz$	_	-68	_	dB
$C_{Mux(off)}$	Mux Off Capacitance	$EA = EB = V_{CC}, V_{IN} = V_{OUT} = 0V$	_	5.6	_	pF
$C_{\text{Demux(off)}}$	Demux Off Capacitance	$EA = EB = V_{CC}, V_{IN} = V_{OUT} = 0V$	_	7.4	_	pF
C _{Mux(on)}	Mux On Capacitance	$EA = EB = 0V, V_{IN} = V_{OUT} = 0V$	_	12	_	pF
$C_{Demux(on)}$	Mux On Capacitance	$EA = EB = 0V, V_{IN} = V_{OUT} = 0V$	_	15	_	pF
Q _{CI}	Charge Injection		_	1.5	_	рC

Notes

MDSA-00006-01

- 1. Typical values indicate $V_{CC} = 5.0V$ and $T_A = 25$ °C.
- 2. Guaranteed by design, not subject to production test.
- 3. Measured by voltage drop between A/B and Y pins at indicated current through the switch. On-resistance is determined by the lower of the voltages on the two (I,Y) pins.
- 4. $\Delta r_{DS(on)}$ compares on-resistance at the specified V_{IN} Values.
- 5. The bus switch contributes no group delay other than the RC delay of the on-resistance of the switch and load capacitance. Group delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

Table 5. Power Supply Characteristics

Symbol	Parameter	Test Conditions(1)	Max	Unit
I _{CCQ}	Quiescent Power	$V_{CC} = Max., V_{IN} = GND \text{ or } V_{CC}, f = 0$	3	μΑ

TYPICAL CHARACTERISTICS

Figure 3. Off-isolation and Crosstalk vs. Frequency

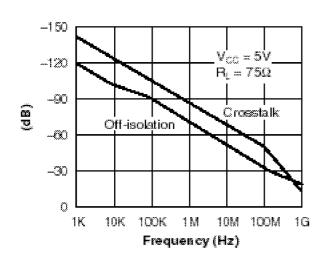
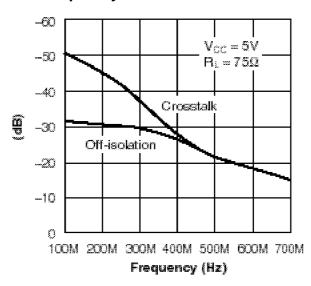


Figure 4. Off-isolation and Crosstalk vs. Frequency



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TYPICAL CHARACTERISTICS (continued)

Figure 5. Off-isolation and Crosstalk vs. Frequency

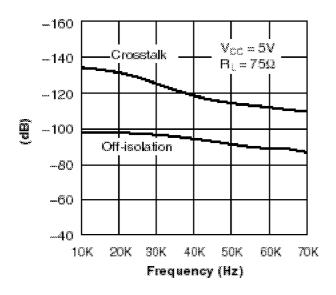


Figure 7. Insertion Loss vs. Frequency

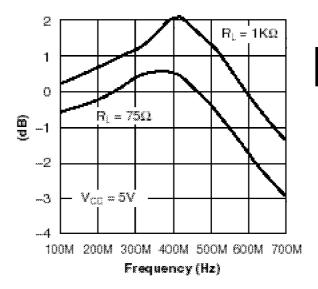


Figure 6. Insertion Loss vs. Frequency

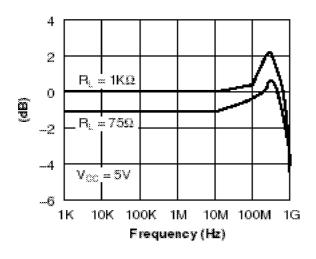
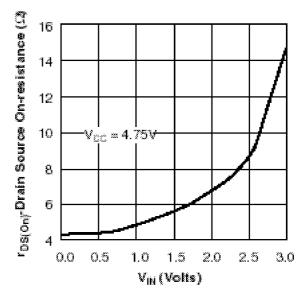
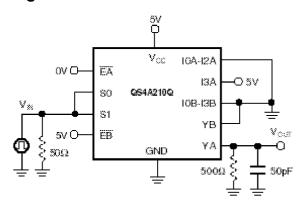


Figure 8. On-resistance vs. V_{IN}



TEST CIRCUITS

Figure 9. Transition Time



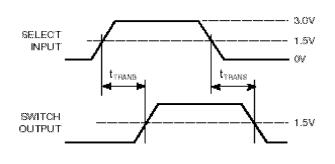
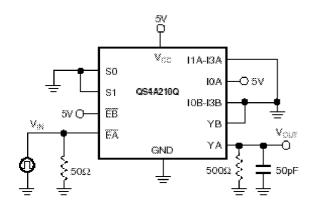


Figure 10. Enable Switching Time



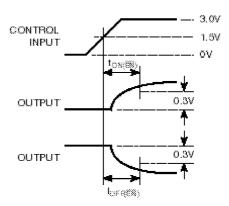
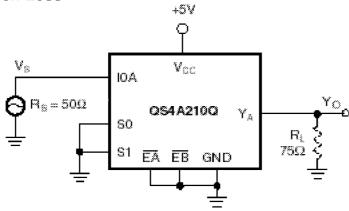


Figure 11. Insertion Loss

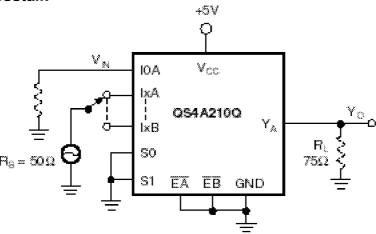


Note: Insertion Loss = $20 \log |V_O/V_S|$

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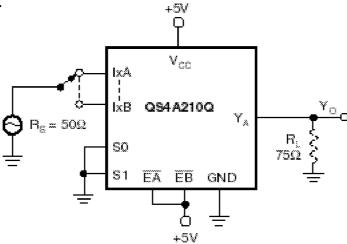
TEST CIRCUITS (continued)

Figure 12. Crosstalk



Note: Crosstalk = $20 \log |V_O/V_S|$

Figure 13. Off-isc'---



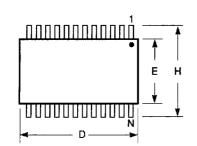
Note: Off-isolation = $20 \log |V_O/V_S|$

Selection Guide and **Packaging Information**



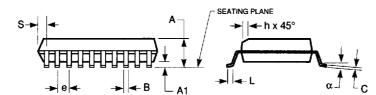
150-MIL QSOP - Package Code Q

Quarter-Size Outline Package Plastic Small Outline Gull-Wing



Notes:

- 1. Refer to applicable symbol list.
- 2. All dimensions are in inches.
- N is the number of lead positions.
 Dimensions D and E are to be measured at maximum material condition but do not include mold flash. Allowable mold flash is 0.006in. per side.
- 5. Lead coplanarity is 0.004in. maximum.



JEDEC#	MO-137AB			MO-137AD		MO-137AE			MO-137AF			
DWG#	PSS-16A			PSS-20A		PSS-24A			PSS-28A			
Symbol	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max
Α .	0.060	0.064	0.068	0.060	0.064	0.068	0.060	0.064	0.068	0.060	0.064	0.068
A1	0.004	0.006	0.008	0.004	0.006	0.008	0.004	0.006	0.008	0.004	0.006	0.008
В	0.009	0.010	0.012	0.009	0.010	0.012	0.009	0.010	0.012	0.009	0.010	0.012
С	0.007	0.008	0.010	0.007	0.008	0.010	0.007	0.008	0.010	0.007	0.008	0.010
D	0.189	0.193	0.197	0.337	0.341	0.344	0.337	0.341	0.344	0.386	0.390	0.394
E	0.150	0.154	0.157	0.150	0.154	0.157	0.150	0.154	0.157	0.150	0.154	0.157
е	0.025 BSC		0.025 BSC		0.025 BSC		0.025 BSC					
н	0.230	0.236	0.244	0.230	0.236	0.244	0.230	0.236	0.244	0.230	0.236	0.244
h	0.010	0.013	0.016	0.010	0.013	0.016	0.010	0.013	0.016	0.010	0.013	0.016
L	0.016	0.025	0.035	0.016	0.025	0.035	0.016	0.025	0.035	0.016	0.025	0.035
N	16			20		24			28			
α	0°	5°	8°	0°	5°	8°	0°	5°	8°	0°	5°	8°
S	0.006	0.009	0.010	0.056	0.058	0.060	0.031	0.033	0.035	0.031	0.033	0.035